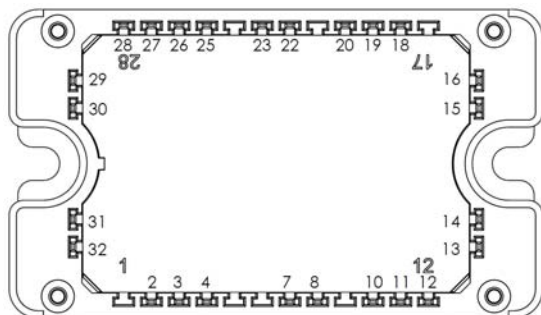
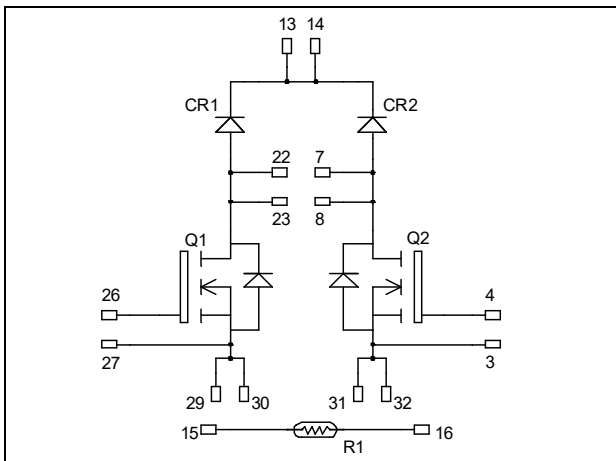


*Dual boost chopper  
Super Junction MOSFET  
Power Module*

**$V_{DSS} = 600V$**

**$R_{DSon} = 24m\Omega$  max @  $T_j = 25^\circ C$**

**$I_D = 95A$  @  $T_c = 25^\circ C$**



All multiple inputs and outputs must be shorted together  
 Example: 13/14 ; 29/30 ; 22/23 ...

**All ratings @  $T_j = 25^\circ C$  unless otherwise specified**

**Absolute maximum ratings** (per super junction MOSFET)

Symbol	Parameter	Max ratings	Unit
$V_{DSS}$	Drain - Source Voltage	600	V
$I_D$	Continuous Drain Current	$T_c = 25^\circ C$	95
		$T_c = 80^\circ C$	70
$I_{DM}$	Pulsed Drain current	260	A
$V_{GS}$	Gate - Source Voltage	$\pm 20$	V
$R_{DSon}$	Drain - Source ON Resistance	24	$m\Omega$
$P_D$	Power Dissipation	$T_c = 25^\circ C$	462
$I_{AR}$	Avalanche current (repetitive and non repetitive)	15	A
$E_{AR}$	Repetitive Avalanche Energy	3	mJ
$E_{AS}$	Single Pulse Avalanche Energy	1900	

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

## Electrical Characteristics (per super junction MOSFET)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 600V$			350	$\mu A$
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 47.5A$			24	$m\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$	2.1	3	3.9	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$			200	nA

## Dynamic Characteristics (per super junction MOSFET)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V ; V_{DS} = 25V$ $f = 1MHz$		14.4		nF
$C_{oss}$	Output Capacitance			17		
$Q_g$	Total gate Charge	$V_{GS} = 10V$ $V_{Bus} = 300V$ $I_D = 95A$		300		nC
$Q_{gs}$	Gate – Source Charge			68		
$Q_{gd}$	Gate – Drain Charge			102		
$T_{d(on)}$	Turn-on Delay Time	<b>Inductive Switching (125°C)</b> $V_{GS} = 10V$ $V_{Bus} = 400V$ $I_D = 95A$ $R_G = 2.5\Omega$		21		ns
$T_r$	Rise Time			30		
$T_{d(off)}$	Turn-off Delay Time			100		
$T_f$	Fall Time			45		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 25°C</b> $V_{GS} = 10V ; V_{Bus} = 400V$ $I_D = 95A ; R_G = 2.5\Omega$		1350		$\mu J$
$E_{off}$	Turn-off Switching Energy			1040		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 125°C</b> $V_{GS} = 10V ; V_{Bus} = 400V$ $I_D = 95A ; R_G = 2.5\Omega$		2200		$\mu J$
$E_{off}$	Turn-off Switching Energy			1270		
$R_{thJC}$	Junction to Case Thermal Resistance				0.27	°C/W

## Chopper diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage				600	V
$I_{RM}$	Reverse Leakage Current	$V_R = 600V$			100	$\mu A$
$I_F$	DC Forward Current	$T_c = 80^\circ C$		100		A
$V_F$	Diode Forward Voltage	$I_F = 100A$		1.6	2	V
		$I_F = 200A$		2		
		$I_F = 100A, T_j = 125^\circ C$		1.3		
$t_{rr}$	Reverse Recovery Time	$I_F = 100A$ $V_R = 400V$ $di/dt = 200A/\mu s$	$T_j = 25^\circ C$	160		ns
			$T_j = 125^\circ C$	220		
$Q_{rr}$	Reverse Recovery Charge	$T_j = 25^\circ C$ $T_j = 125^\circ C$		290		nC
				1530		
$R_{thJC}$	Junction to Case Thermal Resistance				0.55	°C/W

## Thermal and package characteristics

Symbol	Characteristic	Min	Max	Unit
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz	4000		V
T <sub>J</sub>	Operating junction temperature range	-40	150	°C
T <sub>JOP</sub>	Recommended junction temperature under switching conditions	-40	T <sub>Jmax</sub> -25	
T <sub>STG</sub>	Storage Temperature Range	-40	125	
T <sub>C</sub>	Operating Case Temperature	-40	125	
Torque	Mounting torque	To heatsink	M4	
Wt	Package Weight		110	g

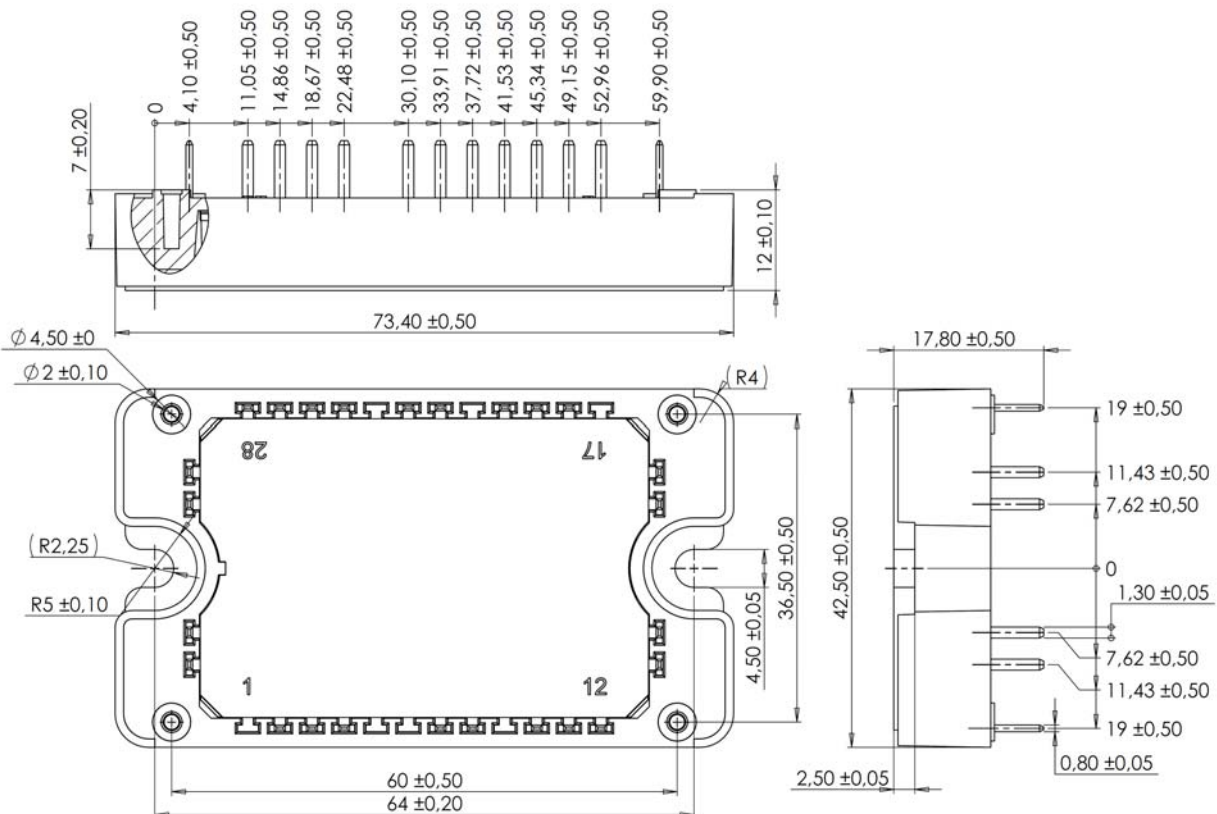
## Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Typ	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		50		kΩ
ΔR <sub>25</sub> /R <sub>25</sub>			5		%
B <sub>25/85</sub>	T <sub>25</sub> = 298.15 K		3952		K
ΔB/B	T <sub>C</sub> = 100°C		4		%

$$R_T = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$

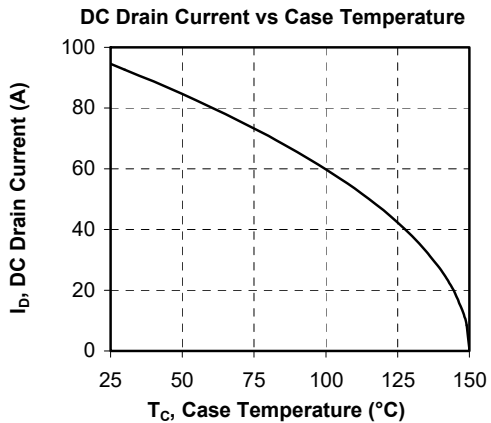
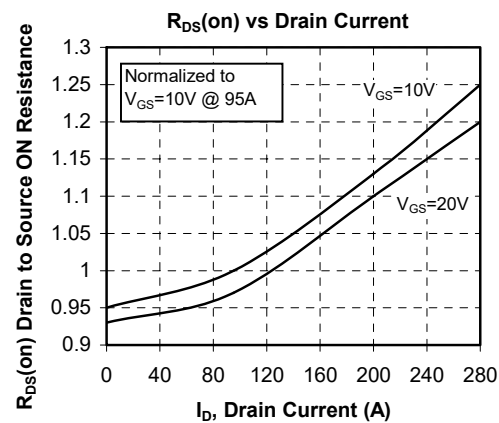
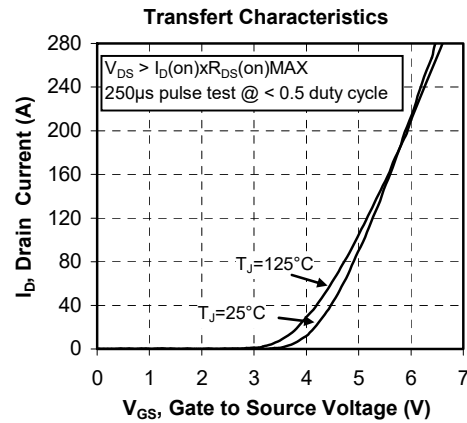
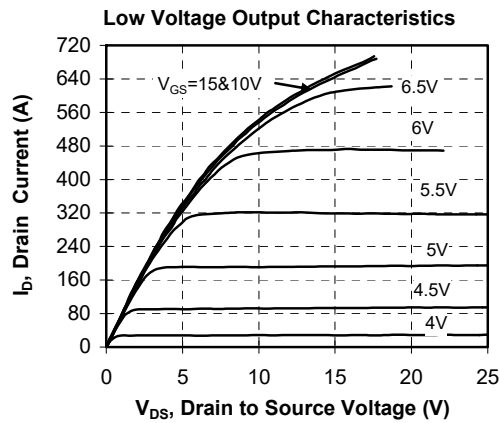
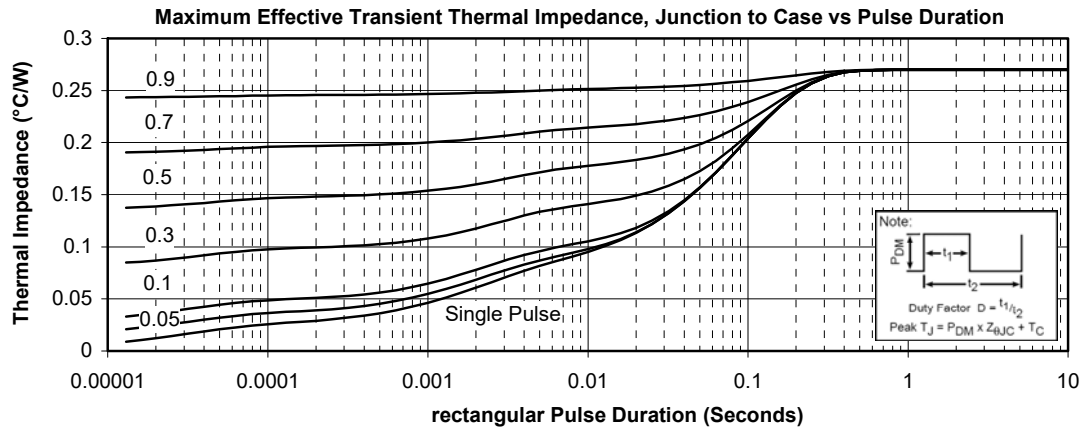
T: Thermistor temperature  
R<sub>T</sub>: Thermistor value at T

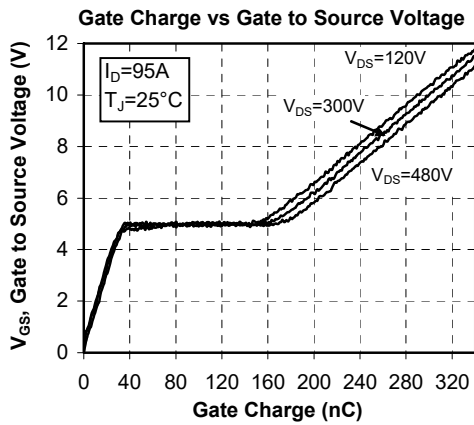
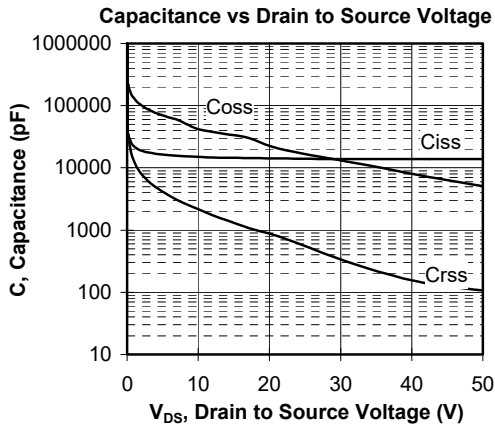
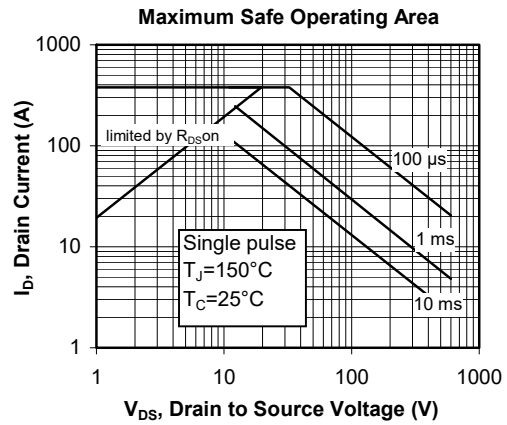
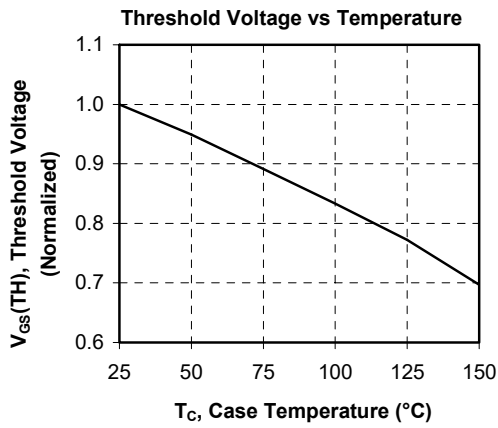
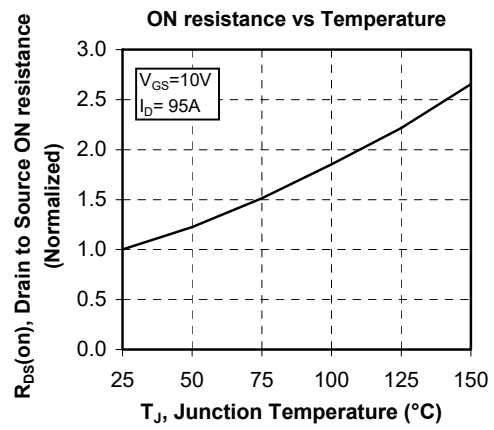
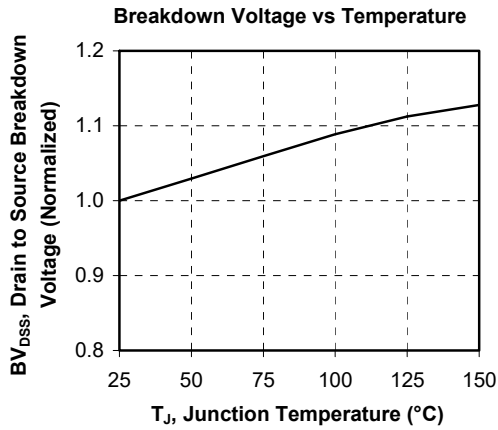
## Package outline (dimensions in mm)

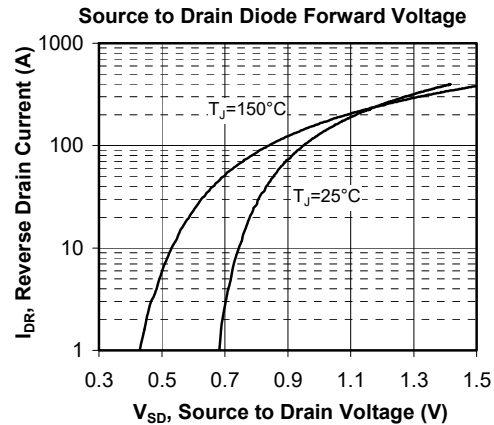
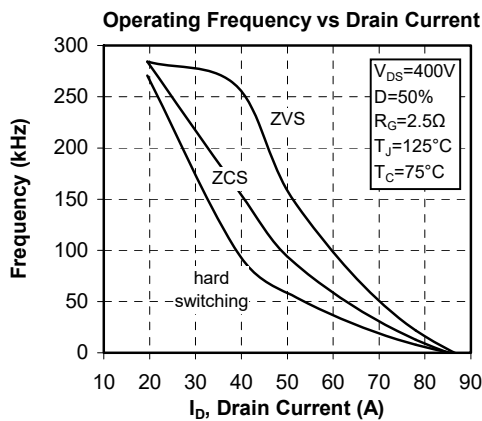
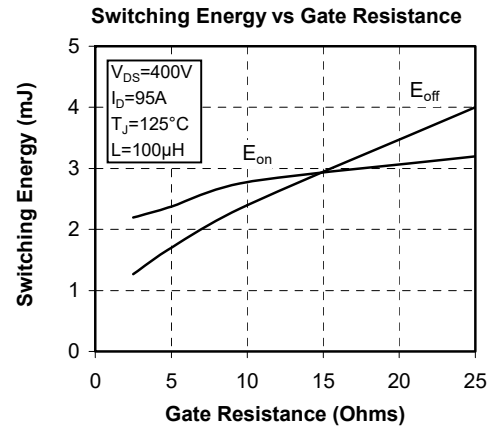
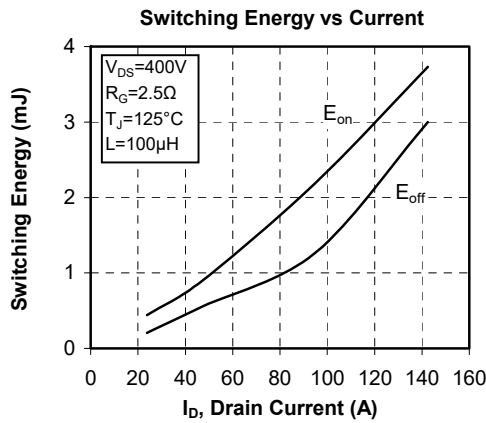
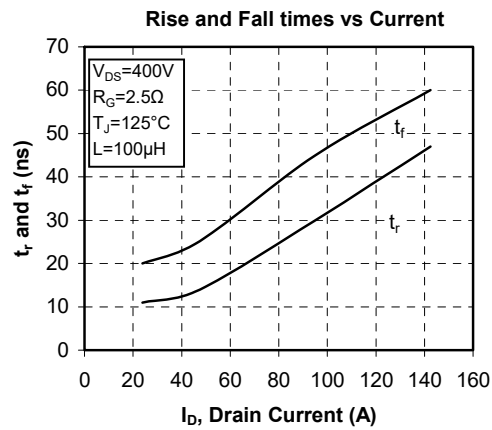
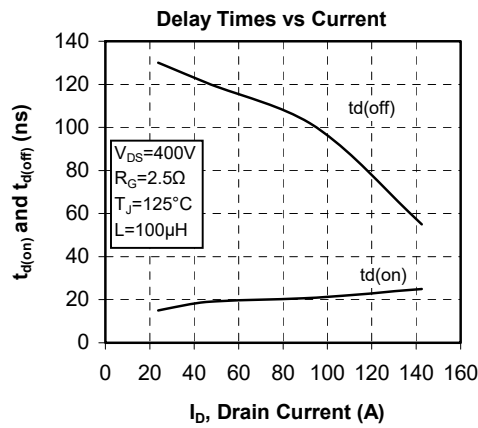


See application note 1906 - Mounting Instructions for SP3F Power Modules on [www.microsemi.com](http://www.microsemi.com)

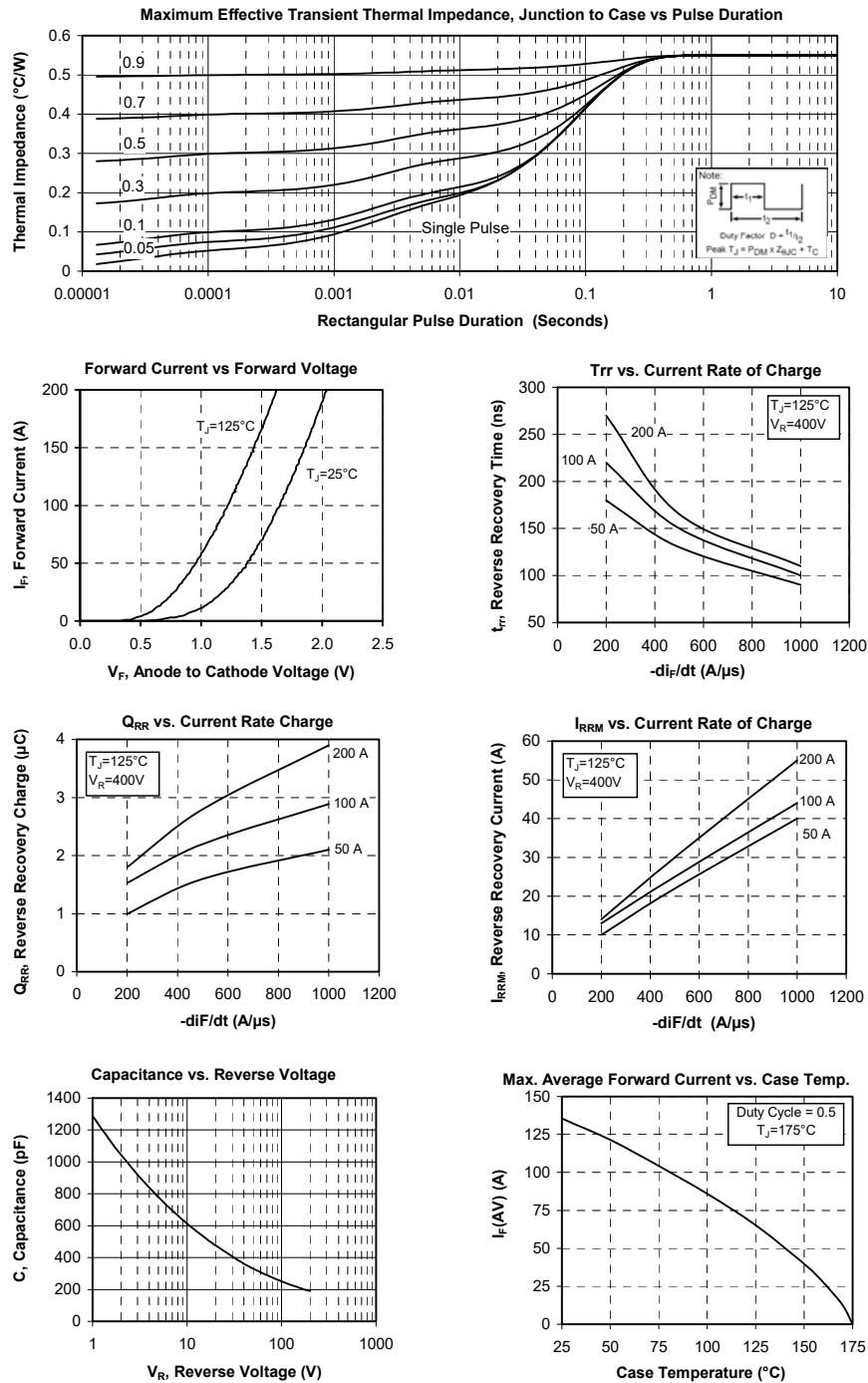
## Typical Super junction MOSFET Performance Curve







## Typical chopper diode performance curve



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